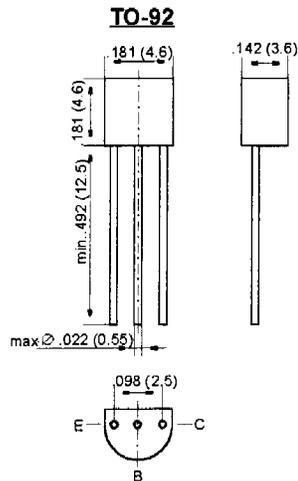


2N4126

Small Signal Transistors (PNP)



Dimensions in inches and (millimeters)

FEATURES

- ◆ PNP Silicon Epitaxial Transistor for switching and amplifier applications. Especially suit-able for AF-driver and low-power output stages.
- ◆ As complementary type, the NPN transistor 2N4124 is recommended.

MECHANICAL DATA

Case: TO-92 Plastic Package

Weight: approx. 0.18 g

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

	Symbol	Value	Unit
Collector-Emitter Voltage	$-V_{CEO}$	25	V
Collector-Base Voltage	$-V_{CBO}$	25	V
Emitter-Base Voltage	$-V_{EBO}$	4	V
Collector Current	$-I_C$	200	mA
Peak Collector Current	$-I_{CM}$	800	mA
Base Current	$-I_B$	50	mA
Power Dissipation at $T_{amb} = 25\text{ }^\circ\text{C}$	P_{tot}	625 ¹⁾	mW
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_s	-65 to +150	°C

¹⁾ Valid provided that leads are kept at ambient temperature at a distance of 2 mm from case.



2N4126

ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain at $V_{CE} = -1$ V, $I_C = -2.0$ mA at $V_{CE} = -1$ V, $I_C = -50$ mA	h_{FE} h_{FE}	120 –	– 60	360 –	– –
Collector Cutoff Current at $V_{CB} = -20$ V	$-I_{CBO}$	–	–	50	nA
Emitter Cutoff Current at $V_{EB} = -3$ V	$-I_{EBO}$	–	–	50	nA
Collector Saturation Voltage at $I_C = -50$ mA, $I_B = -5$ mA	$-V_{CESAT}$	–	–	0.4	V
Base Saturation Voltage at $I_C = -50$ mA, $I_B = -5$ mA	$-V_{BESAT}$	–	–	0.95	V
Collector-Emitter Breakdown Voltage at $I_C = -1$ mA	$-V_{(BR)CEO}$	25	–	–	V
Collector-Base Breakdown Voltage at $I_C = -10$ μ A	$-V_{(BR)CBO}$	25	–	–	V
Emitter-Base Breakdown Voltage at $I_E = -10$ μ A	$-V_{(BR)EBO}$	4	–	–	V
Gain-Bandwidth Product at $V_{CE} = -5$ V, $I_C = -10$ mA, $f = 50$ MHz	f_T	–	200	–	MHz
Collector-Base Capacitance at $V_{CB} = -10$ V, $f = 1$ MHz	C_{CBO}	–	12	–	pF
Thermal Resistance Junction to Ambient Air	R_{thJA}	–	–	200 ¹⁾	K/W

¹⁾ Valid provided that leads are kept at ambient temperature at a distance of 2 mm from case.